# NSN 5961-00-417-8047

Transistor - Page 1 of 1



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**Inclosure Material:** 

Metal

**Overall Length:** 

0.300 inches

#### **Overall Diameter:**

0.820 inches

## **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current

## Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

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